



# Cascadable Silicon Bipolar MMIC Amplifier

## Technical Data

### MSA-0611

#### Features

- **Cascadable 50  $\Omega$  Gain Block**
- **3 dB Bandwidth:**  
DC to 0.7 GHz
- **High Gain:**  
18.0 dB Typical at 0.5 GHz
- **Low Noise Figure:**  
3.0 dB Typical at 0.5 GHz
- **Low Cost Surface Mount Plastic Package**
- **Tape-and-Reel Packaging Option Available<sup>[1]</sup>**

#### Note:

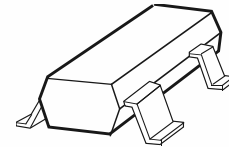
1. Refer to PACKAGING section "Tape-and-Reel Packaging for Semiconductor Devices".

#### Description

The MSA-0611 is a low cost silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in the surface mount plastic SOT-143 package. This MMIC is designed for use as a general purpose 50  $\Omega$  gain block. Typical applications include narrow and broad band IF and RF amplifiers in commercial and industrial applications.

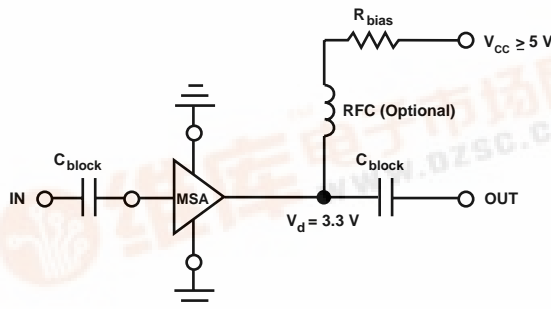
The MSA-series is fabricated using HP's 10 GHz  $f_T$ , 25 GHz  $f_{MAX}$ , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent

#### SOT-143 Package



performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

#### Typical Biasing Configuration



## MSA-0611 Absolute Maximum Ratings

Parameter	Absolute Maximum <sup>[1]</sup>
Device Current	40 mA
Power Dissipation <sup>[2,3]</sup>	125 mW
RF Input Power	+13 dBm
Junction Temperature	150°C
Storage Temperature	-65 to 150°C

### Thermal Resistance<sup>[2,4]</sup>:

$$\theta_{jc} = 505^{\circ}\text{C}/\text{W}$$

#### Notes:

1. Permanent damage may occur if any of these limits are exceeded.
2.  $T_{\text{CASE}} = 25^{\circ}\text{C}$ .
3. Derate at 2.0 mW/°C for  $T_{\text{C}} > 87^{\circ}\text{C}$ .
4. See MEASUREMENTS section "Thermal Resistance" for more information.

## Electrical Specifications<sup>[1]</sup>, $T_{\text{A}} = 25^{\circ}\text{C}$

Symbol	Parameters and Test Conditions: $I_{\text{d}} = 16 \text{ mA}$ , $Z_{\text{o}} = 50 \Omega$	Units	Min.	Typ.	Max.
GP	Power Gain ( $ S_{21} ^2$ ) f = 0.1 GHz f = 0.5 GHz	dB	16.0	19.5 18.0	
$\Delta\text{GP}$	Gain Flatness f = 0.1 to 0.5 GHz	dB		$\pm 0.8$	
$f_{3 \text{ dB}}$	3 dB Bandwidth	GHz		0.7	
VSWR	Input VSWR f = 0.1 to 1.5 GHz			1.6:1	
	Output VSWR f = 0.1 to 1.5 GHz			1.5:1	
NF	50 $\Omega$ Noise Figure f = 0.5 GHz	dB		3.0	
$P_{1 \text{ dB}}$	Output Power at 1 dB Gain Compression f = 0.5 GHz	dBm		2.0	
IP <sub>3</sub>	Third Order Intercept Point f = 0.5 GHz	dBm		14.0	
$t_{\text{D}}$	Group Delay f = 0.5 GHz	psec		225	
$V_{\text{d}}$	Device Voltage $T_{\text{C}} = 25^{\circ}\text{C}$	V	2.6	3.3	4.0
dV/dT	Device Voltage Temperature Coefficient	mV/°C		-8.0	

#### Notes:

1. The recommended operating current range for this device is 12 to 20 mA. Typical gain performance as a function of current is on the following page.

## Part Number Ordering Information

Part Number	No. of Devices	Container
MSA-0611-TR1	3000	7" Reel
MSA-0611-BLK	100	Antistatic Bag

For more information, see "Tape and Reel Packaging for Semiconductor Devices".

### MSA-0611 Typical Scattering Parameters ( $Z_0 = 50 \Omega$ , $T_A = 25^\circ\text{C}$ , $I_d = 16 \text{ mA}$ )

Freq. GHz	S <sub>11</sub>		S <sub>21</sub>			S <sub>12</sub>			S <sub>22</sub>		k
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	
0.1	.04	-176	19.6	9.53	170	-23.0	.071	6	.04	-57	1.07
0.2	.03	-163	19.3	9.25	160	-22.7	.073	10	.07	-82	1.07
0.3	.03	-149	18.9	8.79	150	-22.8	.072	14	.09	-97	1.10
0.4	.04	-132	18.5	8.38	141	-21.9	.080	17	.11	-111	1.07
0.5	.05	-127	18.0	7.96	133	-21.6	.083	21	.13	-122	1.07
0.6	.07	-123	17.3	7.33	125	-21.2	.087	23	.15	-131	1.07
0.8	.10	-129	16.2	6.46	111	-19.7	.103	25	.17	-147	1.04
1.0	.13	-139	15.0	5.64	98	-19.0	.112	28	.18	-160	1.06
1.5	.22	-164	12.5	4.22	73	-17.1	.139	25	.19	175	1.07
2.0	.31	171	10.1	3.20	53	-16.1	.157	21	.19	160	1.13
2.5	.39	158	8.1	2.55	42	-15.4	.169	22	.20	153	1.19
3.0	.45	144	6.3	2.07	28	-15.0	.178	18	.19	150	1.26
3.5	.50	132	4.7	1.72	16	-14.6	.185	15	.16	152	1.33
4.0	.52	121	3.4	1.48	4	-14.1	.197	11	.14	166	1.37

A model for this device is available in the DEVICE MODELS section.

### Typical Performance, $T_A = 25^\circ\text{C}$

(unless otherwise noted)

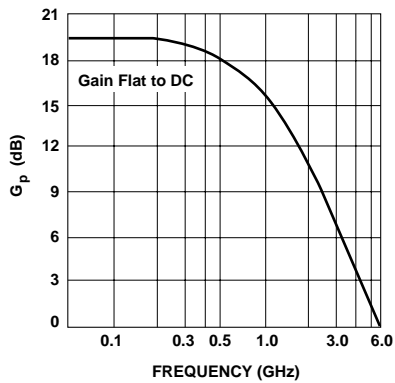


Figure 1. Power Gain vs. Frequency,  $T_A = 25^\circ\text{C}$ ,  $I_d = 16 \text{ mA}$ .

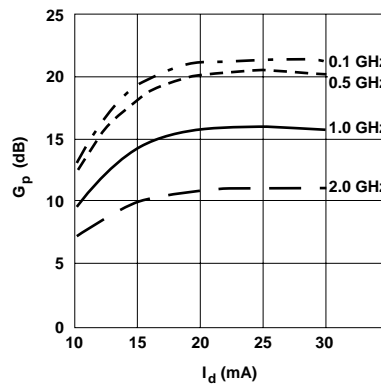


Figure 2. Power Gain vs. Current.

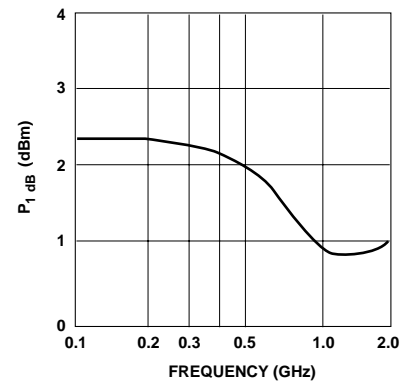


Figure 3. Output Power @ 1 dB Gain Compression vs. Frequency,  $I_d = 16 \text{ mA}$ .

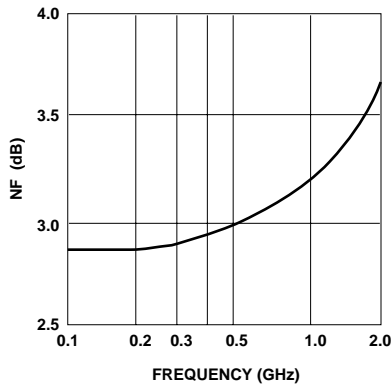
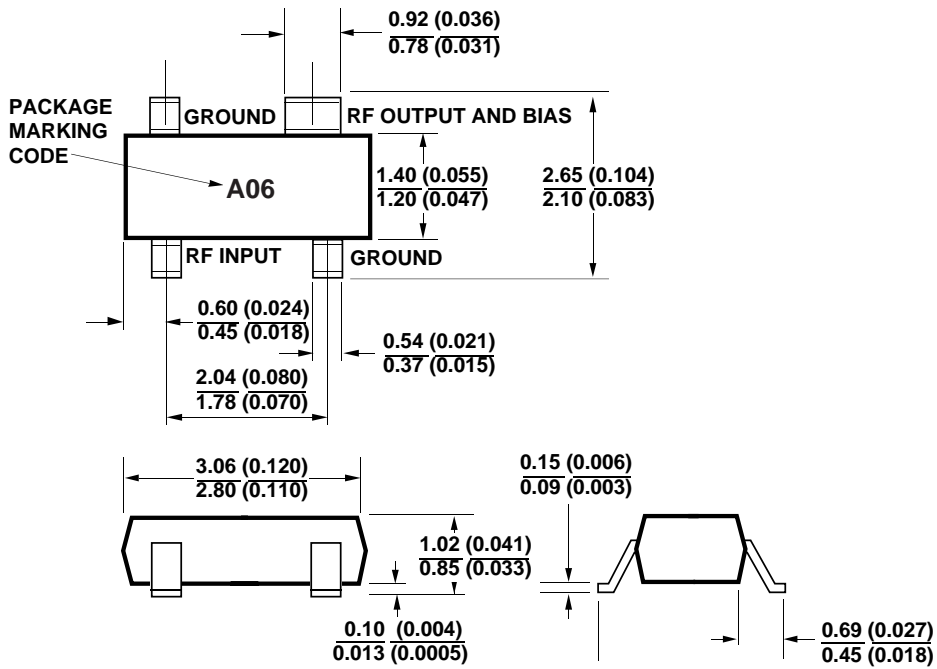


Figure 4. Noise Figure vs. Frequency,  $I_d = 16 \text{ mA}$ .

## SOT-143 Package Dimensions



DIMENSIONS ARE IN MILLIMETERS (INCHES)